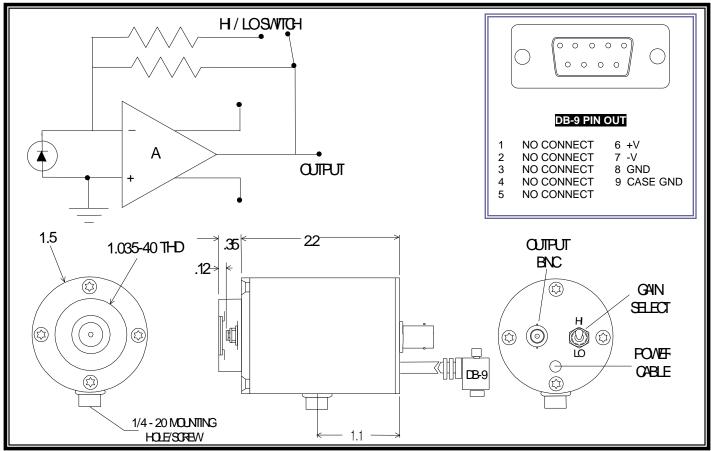


UV SILICON PHOTODIODE RECEIVERS



This unit is a high performance photodiode/receiver operated with at ambient temperature with a dual gain FET input transimpedence amplifier. The output voltage is proportional to the input signal current: $V_{out} = I_{signal} \cdot R_f .$ The PD/AMP is a DC coupled dual gain system. Care should be taken in shielding the unit from stray light during operation to prevent saturation of the amplifier (and potential failure).

SPECIFICATIONS	
Part Number	UVS - 010 - H
Active Area	1.0 mm dia
Operating Wavelength- μm	0.2 - 1.0
Responsivity- V/W @ pk	.5 x 10 ⁹ / 10 ⁸
Noise- V/Hz ^{1/2}	5.0 x 10 ⁻⁶ / 10 ⁻⁶
NEP- W/Hz ^{1/2} @ pk	< 1.0 x 10 ⁻¹⁴
Bandwidth (-3dB)- Hz	DC - 500 / 2k
Power Requirements	+/- 9 VDC to +/- 15 VDC
Connections	BNC signal output. Shielded power cable terminated with a DB-9 connector directly couples the unit with the PS -1 Low Noise Power Supply.